

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6020AK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =60V,I_D =20A

 $R_{DS(ON)}$ <35m Ω @ V_{GS} =10V

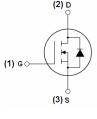
 $R_{DS(ON)}$ <40m Ω @ V_{GS} =4.5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED! 100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6020AK	NCE6020AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	20	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	14	Α
Pulsed Drain Current	I _{DM}	60	А
Maximum Power Dissipation	P _D	45	W
Derating factor		0.3	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	72	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	℃

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ heta JC}$	3.3	°C/W



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Electrical Characteristics (T_c=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA 60		-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1.2	1.6	2.5	V
Drain Source On State Registeres	Б	V _{GS} =10V, I _D =10A	-	24	35	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =10A		30	40	11112
Forward Transconductance	g FS	V _{DS} =5V,I _D =10A	11	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ -20\/\/ -0\/	-	973.2	-	PF
Output Capacitance	Coss	V_{DS} =30V, V_{GS} =0V, F=1.0MHz	-	61.2	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0IVID2	-	58.8	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	7	-	nS
Turn-on Rise Time	t _r	V_{DD} =30V, R_L =3 Ω	-	20	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =3 Ω	-	16	-	nS
Turn-Off Fall Time	t _f		-	23	-	nS
Total Gate Charge	Q_g	V 20VI 40A	-	25		nC
Gate-Source Charge	Q_{gs}	V _{DS} =30V,I _D =10A,	-	4.5		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	6.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V _{GS} =0V,I _S =10A	-		1.2	V
Diode Forward Current (Note 2)	I _S		-	-	20	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =10A	-	29	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	49	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

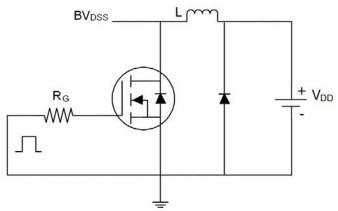
Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production **5.** EAS condition:Tj=25 $^{\circ}$ C,V_{DD}=30V,V_G=10V,L=0.5mH,Rg=25 Ω

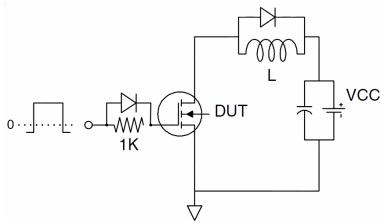


Test Circuit

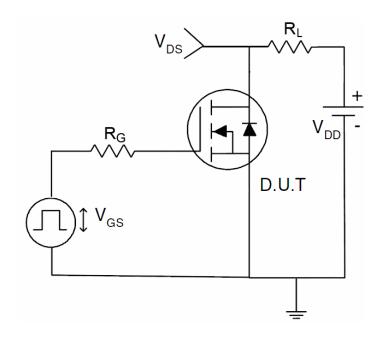
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)

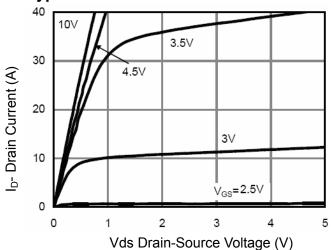


Figure 1 Output Characteristics

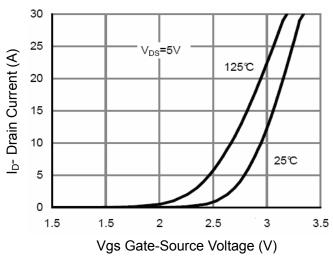


Figure 2 Transfer Characteristics

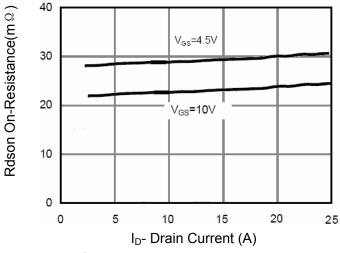


Figure 3 Rdson- Drain Current

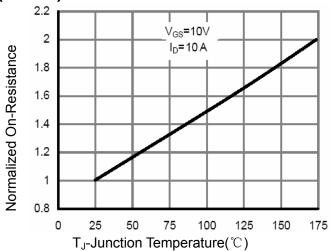


Figure 4 Rdson-Junction Temperature

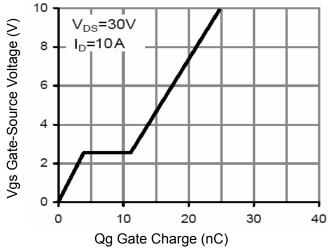


Figure 5 Gate Charge

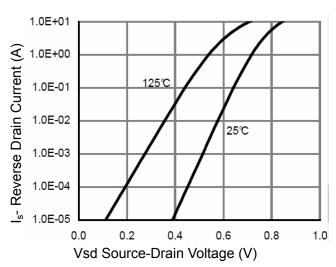


Figure 6 Source- Drain Diode Forward



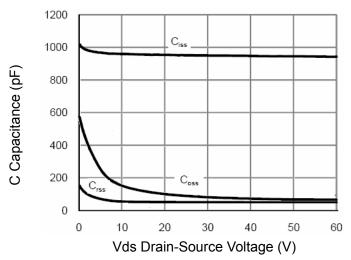


Figure 7 Capacitance vs Vds

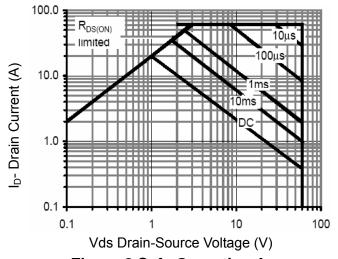


Figure 8 Safe Operation Area

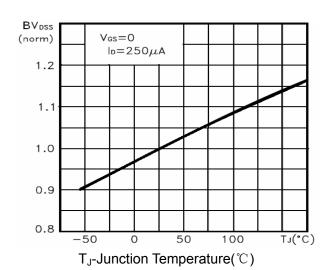


Figure 9 BV_{DSS} vs Junction Temperature

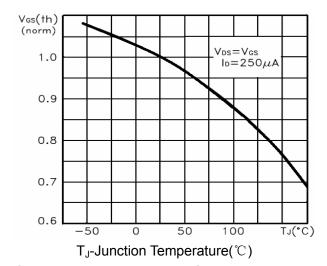
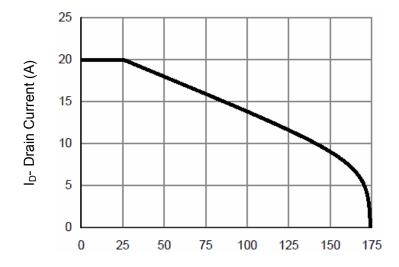


Figure 10 V_{GS(th)} vs Junction Temperature



 $T_{J}\text{-Junction Temperature}(^{\circ}\!\mathbb{C}\,)$

Figure 11 Current De-rating



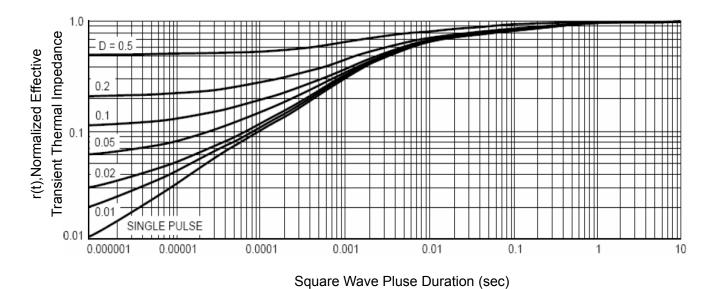
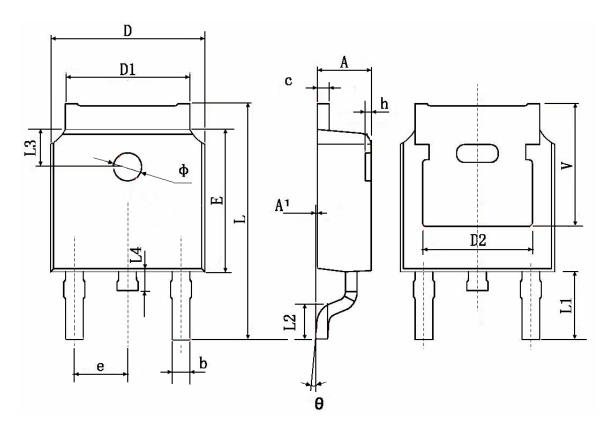


Figure 12 Normalized Maximum Transient Thermal Impedance



TO-252 Package Information



Compleal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.83	30 TYP.	0.190	TYP.	
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.90	0 TYP.	0.201 0.190 TY 0.236 0.086 0.386 0.114 TY 0.055 0.063 TY 0.024	TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.60	1.600 TYP.		TYP.	
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.35	0 TYP.	0.211 TYP.		

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NCE6020AK

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